

L Number	Hits	Search Text	DB	Time stamp
15	41178	gate and (capacitor or capacitance or capacitive\$2) and (insulat\$4 or dielectric\$3) and ((semiconduct\$3 near2 island) or transistor or MOSFET\$1 or FET\$1)	USPAT; US-PGPUB; EPO; JPO	2003/08/20 23:03
16	47885	gate and (capacitor or capacitance or capacitive\$2) and (insulat\$4 or dielectric\$3) and ((semiconduct\$3 near2 island) or transistor\$1 or MOSFET\$1 or FET\$1 or JFET\$1)	USPAT; US-PGPUB; EPO; JPO	2003/08/20 23:03
17	39044	gate and (capacitor or capacitance or capacitive\$2) and (insulat\$4 or dielectric\$3) and ((semiconduct\$3 near2 island\$1) or transistor\$1 or MOSFET\$1 or FET\$1 or JFET\$1)	USPAT; US-PGPUB; EPO; JPO	2003/08/20 23:03
18	24880	((313/\$7.ccls. or 250/\$7.ccls. or 257/\$7.ccls. or 315/\$7.ccls.) and (gate and (capacitor or capacitance or capacitive\$2) and (insulat\$4 or dielectric\$3) and ((semiconduct\$3 near2 island) or transistor\$1 or MOSFET\$1 or FET\$1 or JFET\$1)))	USPAT; US-PGPUB; EPO; JPO	2003/08/20 23:05
19	2757	((light\$4 adj2 emit\$5) or EL or OLED or electroluminescen\$4 or luminescen\$4) and ((313/\$7.ccls. or 250/\$7.ccls. or 257/\$7.ccls. or 315/\$7.ccls.) and (gate and (capacitor or capacitance or capacitive\$2) and (insulat\$4 or dielectric\$3) and ((semiconduct\$3 near2 island) or transistor\$1 or MOSFET\$1 or FET\$1 or JFET\$1)))	USPAT; US-PGPUB; EPO; JPO	2003/08/20 23:07
20	1958	((light\$4 adj2 emit\$5) or EL or OLED or electroluminescen\$4 or luminescen\$4) and ((313/\$7.ccls. or 250/\$7.ccls. or 257/\$7.ccls. or 315/\$7.ccls.) and (gate and (capacitor or capacitance or capacitive\$2) and (insulat\$4 or dielectric\$3) and ((semiconduct\$3 near2 island) or transistor\$1 or MOSFET\$1 or FET\$1 or JFET\$1)))	USPAT; EPO; JPO	2003/08/20 23:07
21	557	channel\$1 and (impurit\$3) and (((light\$4 adj2 emit\$5) or EL or OLED or electroluminescen\$4 or luminescen\$4) and ((313/\$7.ccls. or 250/\$7.ccls. or 257/\$7.ccls. or 315/\$7.ccls.) and (gate and (capacitor or capacitance or capacitive\$2) and (insulat\$4 or dielectric\$3) and ((semiconduct\$3 near2 island) or transistor\$1 or MOSFET\$1 or FET\$1 or JFET\$1))))	USPAT; US-PGPUB; EPO; JPO	2003/08/20 23:07
22	163	cathode and anode and (channel\$1 and (impurit\$3) and (((light\$4 adj2 emit\$5) or EL or OLED or electroluminescen\$4 or luminescen\$4) and ((313/\$7.ccls. or 250/\$7.ccls. or 257/\$7.ccls. or 315/\$7.ccls.) and (gate and (capacitor or capacitance or capacitive\$2) and (insulat\$4 or dielectric\$3) and ((semiconduct\$3 near2 island) or transistor\$1 or MOSFET\$1 or FET\$1 or JFET\$1))))))	USPAT; US-PGPUB; EPO; JPO	2003/08/20 23:08

L Number	Hits	Search Text	DB	Time stamp
15	41178	gate and (capacitor or capacitance or capacitive\$2) and (insulat\$4 or dielectric\$3) and ((semiconduct\$3 near2 island) or transistor or MOSFET\$1 or FET\$1)	USPAT; US-PGPUB; EPO; JPO	2003/08/20 23:03
16	47885	gate and (capacitor or capacitance or capacitive\$2) and (insulat\$4 or dielectric\$3) and ((semiconduct\$3 near2 island) or transistor\$1 or MOSFET\$1 or FET\$1 or JFET\$1)	USPAT; US-PGPUB; EPO; JPO	2003/08/20 23:03
17	39044	gate and (capacitor or capacitance or capacitive\$2) and (insulat\$4 or dielectric\$3) and ((semiconduct\$3 near2 island\$1) or transistor\$1 or MOSFET\$1 or FET\$1 or JFET\$1)	USPAT; US-PGPUB; EPO; JPO	2003/08/20 23:03
18	24880	(313/\$7.ccls. or 250/\$7.ccls. or 257/\$7.ccls. or 315/\$7.ccls.) and (gate and (capacitor or capacitance or capacitive\$2) and (insulat\$4 or dielectric\$3) and ((semiconduct\$3 near2 island) or transistor\$1 or MOSFET\$1 or FET\$1 or JFET\$1))	USPAT; US-PGPUB; EPO; JPO	2003/08/20 23:05
19	2757	((light\$4 adj2 emit\$5) or EL or OLED or electroluminescen\$4 or luminescen\$4) and ((313/\$7.ccls. or 250/\$7.ccls. or 257/\$7.ccls. or 315/\$7.ccls.) and (gate and (capacitor or capacitance or capacitive\$2) and (insulat\$4 or dielectric\$3) and ((semiconduct\$3 near2 island) or transistor\$1 or MOSFET\$1 or FET\$1 or JFET\$1)))	USPAT; US-PGPUB; EPO; JPO	2003/08/20 23:07
20	1958	((light\$4 adj2 emit\$5) or EL or OLED or electroluminescen\$4 or luminescen\$4) and ((313/\$7.ccls. or 250/\$7.ccls. or 257/\$7.ccls. or 315/\$7.ccls.) and (gate and (capacitor or capacitance or capacitive\$2) and (insulat\$4 or dielectric\$3) and ((semiconduct\$3 near2 island) or transistor\$1 or MOSFET\$1 or FET\$1 or JFET\$1)))	USPAT; EPO; JPO	2003/08/20 23:09
21	557	channel\$1 and (impurit\$3) and (((light\$4 adj2 emit\$5) or EL or OLED or electroluminescen\$4 or luminescen\$4) and ((313/\$7.ccls. or 250/\$7.ccls. or 257/\$7.ccls. or 315/\$7.ccls.) and (gate and (capacitor or capacitance or capacitive\$2) and (insulat\$4 or dielectric\$3) and ((semiconduct\$3 near2 island) or transistor\$1 or MOSFET\$1 or FET\$1 or JFET\$1))))	USPAT; US-PGPUB; EPO; JPO	2003/08/20 23:10
22	163	cathode and anode and (channel\$1 and (impurit\$3) and (((light\$4 adj2 emit\$5) or EL or OLED or electroluminescen\$4 or luminescen\$4) and ((313/\$7.ccls. or 250/\$7.ccls. or 257/\$7.ccls. or 315/\$7.ccls.) and (gate and (capacitor or capacitance or capacitive\$2) and (insulat\$4 or dielectric\$3) and ((semiconduct\$3 near2 island) or transistor\$1 or MOSFET\$1 or FET\$1 or JFET\$1))))	USPAT; US-PGPUB; EPO; JPO	2003/08/20 23:10
23	2050	((light\$4 adj2 emit\$5) or EL or OLED or electroluminescen\$4 or luminescen\$4 or luminous) and ((313/\$7.ccls. or 250/\$7.ccls. or 257/\$7.ccls. or 315/\$7.ccls.) and (gate and (capacitor or capacitance or capacitive\$2) and (insulat\$4 or dielectric\$3) and ((semiconduct\$3 near2 island) or transistor\$1 or MOSFET\$1 or FET\$1 or JFET\$1)))	USPAT; EPO; JPO	2003/08/20 23:09

24	163	channel\$1 and (impurit\$3) and (cathode and anode and (channel\$1 and (impurit\$3) and (((light\$4 adj2 emit\$5) or EL or OLED or electroluminescen\$4 or luminescen\$4) and ((313/\$7.ccls. or 250/\$7.ccls. or 257/\$7.ccls. or 315/\$7.ccls.) and (gate and (capacitor or capacitance or capacitive\$2) and (insulat\$4 or dielectric\$3) and ((semiconduct\$3 near2 island) or transistor\$1 or MOSFET\$1 or FET\$1 or JFET\$1))))))	USPAT; US-PGPUB; EPO; JPO	2003/08/20 23:10
25	525	channel\$1 and (impurit\$3) and (((light\$4 adj2 emit\$5) or EL or OLED or electroluminescen\$4 or luminescen\$4 or luminous) and ((313/\$7.ccls. or 250/\$7.ccls. or 257/\$7.ccls. or 315/\$7.ccls.) and (gate and (capacitor or capacitance or capacitive\$2) and (insulat\$4 or dielectric\$3) and ((semiconduct\$3 near2 island) or transistor\$1 or MOSFET\$1 or FET\$1 or JFET\$1))))	USPAT; US-PGPUB; EPO; JPO	2003/08/20 23:10
26	156	cathode and anode and (channel\$1 and (impurit\$3) and (((light\$4 adj2 emit\$5) or EL or OLED or electroluminescen\$4 or luminescen\$4 or luminous) and ((313/\$7.ccls. or 250/\$7.ccls. or 257/\$7.ccls. or 315/\$7.ccls.) and (gate and (capacitor or capacitance or capacitive\$2) and (insulat\$4 or dielectric\$3) and ((semiconduct\$3 near2 island) or transistor\$1 or MOSFET\$1 or FET\$1 or JFET\$1))))	USPAT; US-PGPUB; EPO; JPO	2003/08/20 23:10